

FFM101-AF THRU FFM107-AF

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FFM101-AF THRU FFM107-AF

1.0A Surface Mount Fast
Recovery Rectifiers 50V-1000V

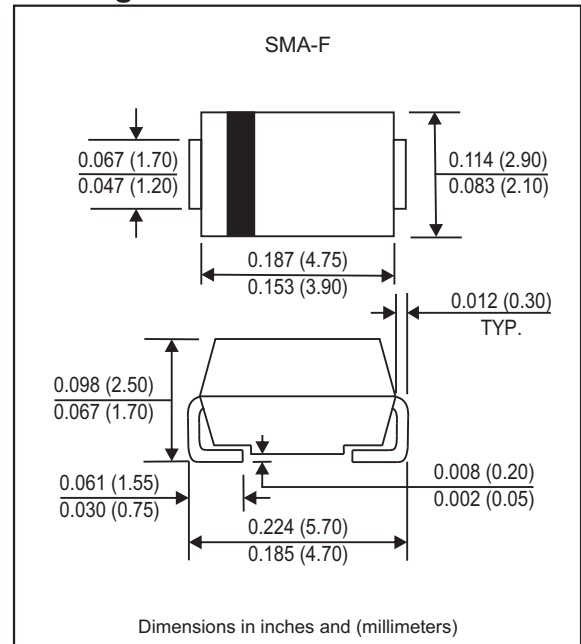
Features

- High current capability
- Fast switching for high efficiency
- High surge current capability
- Glass passivated chip junction
- Lead-free parts meet RoHS requirements
- Suffix "-H" indicates Halogen-free parts, ex. FFM101-AF-H

Mechanical data

- Epoxy: UL94-V0 rated flame retardant
- Case : Molded plastic, DO-214AC / SMA-F
- Terminals : Solder plated, solderable per MIL-AFTD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any
- Weight : Approximated 0.055 gram

Package outline

Maximum ratings (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOLS	FFM101-AF	FFM102-AF	FFM103-AF	FFM104-AF	FFM105-AF	FFM106-AF	FFM107-AF	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum continuous reverse voltage	V_R	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	I_O	1.0							A
Non-repetitive peak forward surge current 8.3ms single half sine-wave (JEDEC methode)	I_{FSM}	30							A
Typical junction capacitance (Note 1)	C_J	15							pF
Operating junction temperature range	T_J	-65 to +150							$^{\circ}\text{C}$
Storage temperature range	T_{STG}	-65 to +150							$^{\circ}\text{C}$

Maximum electrical characteristics (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOLS	FFM101-AF	FFM102-AF	FFM103-AF	FFM104-AF	FFM105-AF	FFM106-AF	FFM107-AF	UNIT
Maximum instantaneous forward voltage at $I_F=1.0\text{A}$	V_F	1.3							V
Maximum reverse leakage current $T_A=25^{\circ}\text{C}$ at rated V_R $T_A=100^{\circ}\text{C}$	I_R	5.0 50.0							μA μA
Maximum reverse recovery time (Note 2)	t_{rr}	150				250	500		ns

Thermal characteristics

PARAMETER	SYMBOLS	FFM101-AF	FFM102-AF	FFM103-AF	FFM104-AF	FFM105-AF	FFM106-AF	FFM107-AF	UNIT
Typical thermal resistance junction to ambient (Note 3)	$R_{\theta JA}$	50							$^{\circ}\text{C/W}$

Notes 1: Measured at 1 MHz and applied reverse voltage of 4.0 VDC

2: Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$

3: Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

Rating and characteristic curves (FFM101-AF THRU FFM107-AF)

Fig.1 TYPICAL FORWARD CHARACTERISTICS

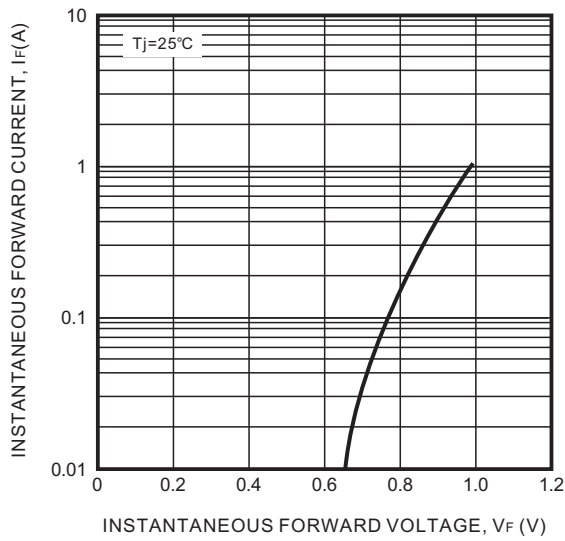


Fig.2 TYPICAL REVERSE CHARACTERISTICS

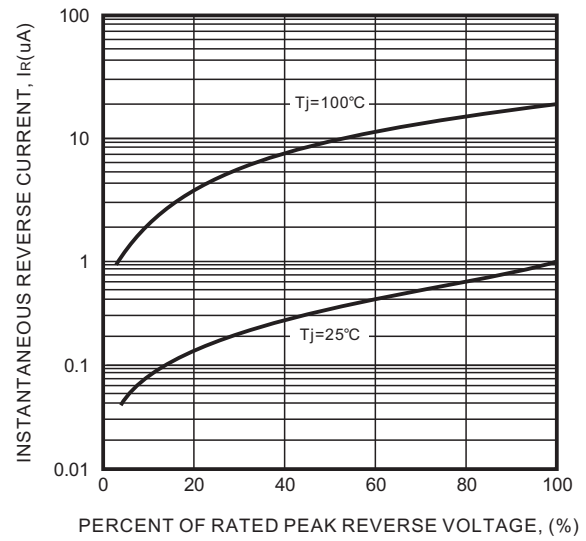


Fig.3 MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

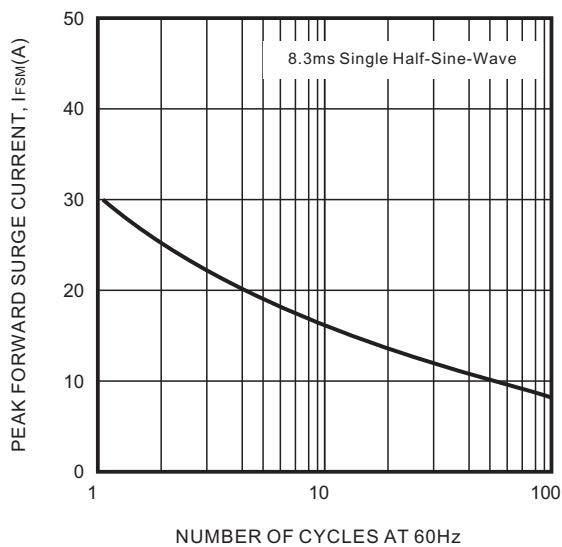


Fig.4 FORWARD CURRENT DERATING CURVE

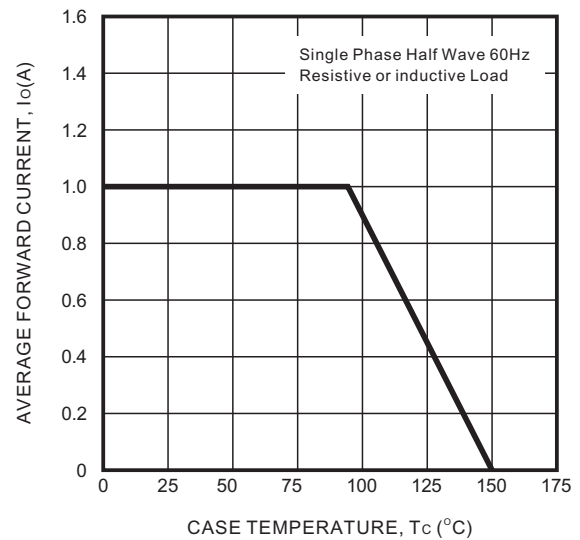
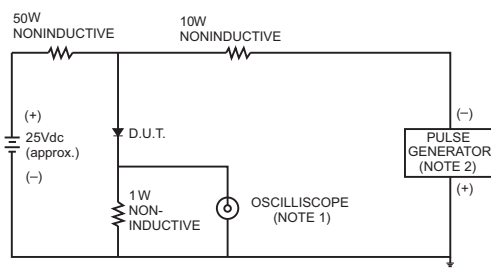
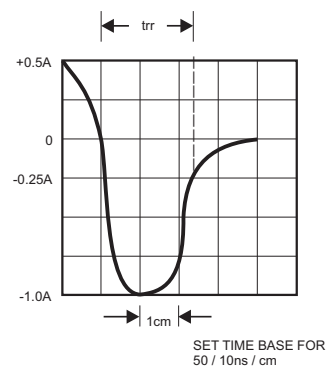


Fig.5 TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.



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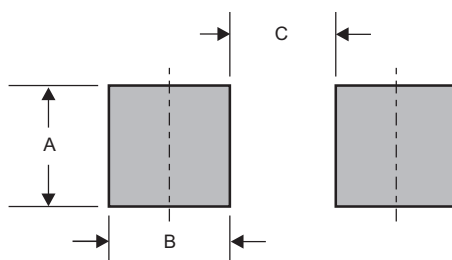
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Marking

Type number	Marking code
FFM101-AF	FR1A
FFM102-AF	FR1B
FFM103-AF	FR1D
FFM104-AF	FR1G
FFM105-AF	FR1J
FFM106-AF	FR1K
FFM107-AF	FR1M

Suggested solder pad layout

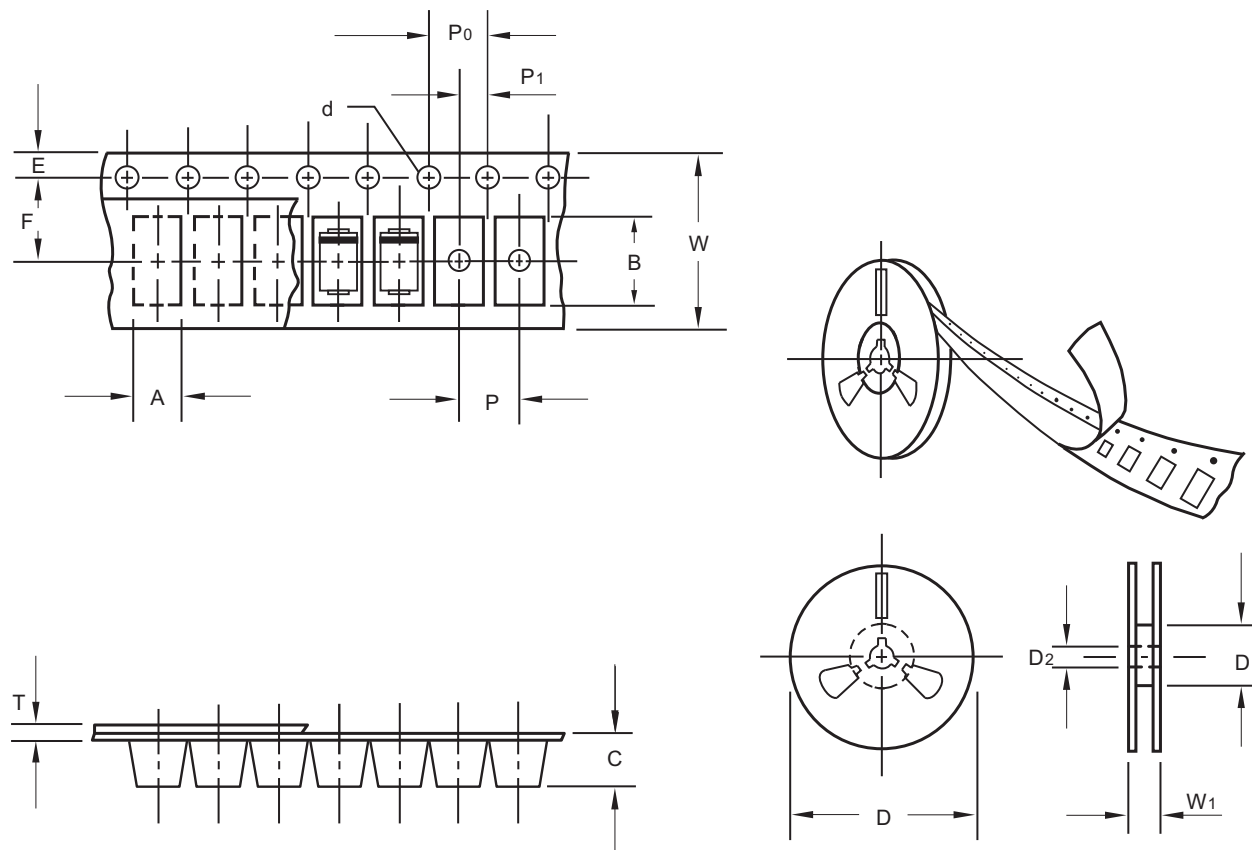


Dimensions in inches and (millimeters)

PACKAGE	A	B	C
SMA-S	0.063 (1.60)	0.059 (1.50)	0.110 (2.80)

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Packing information



unit:mm

Item	Symbol	Tolerance	SMA-F
Carrier width	A	0.1	2.79
Carrier length	B	0.1	5.33
Carrier depth	C	0.1	2.36
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D ₁	min	72.00
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D ₁	min	62.00
Feed hole diameter	D ₂	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	5.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P ₀	0.1	4.00
Embossment center	P ₁	0.1	2.00
Overall tape thickness	T	0.1	0.30
Tape width	W	0.3	12.00
Reel width	W ₁	1.0	18.00

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

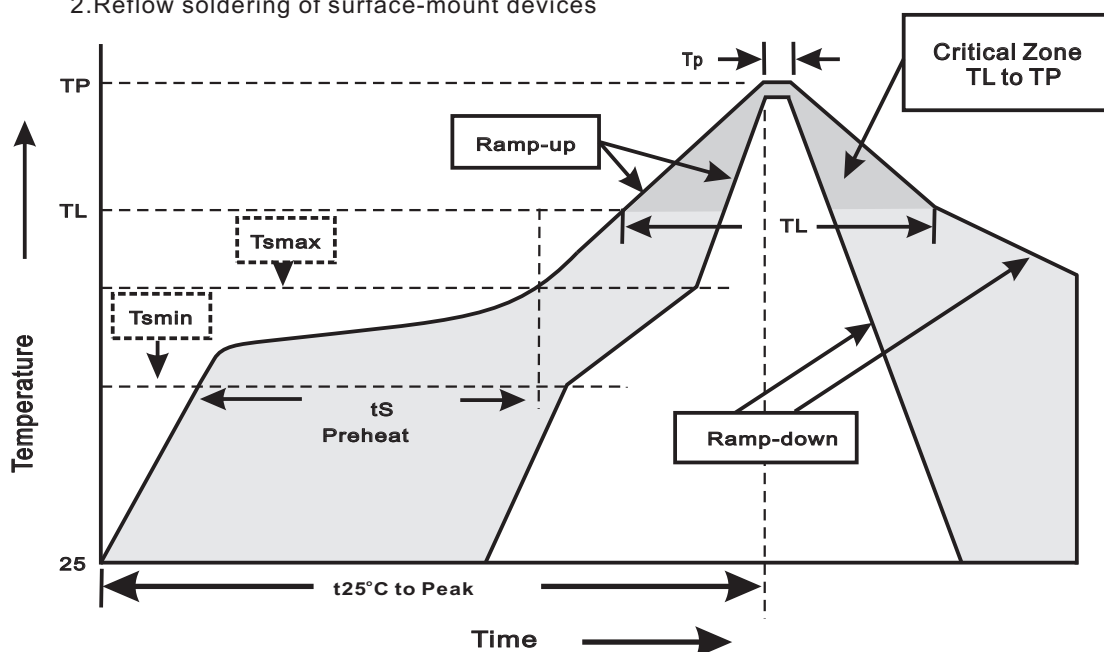
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Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMA-F	13"	5,000	4.0	10,000	335*335*38	330	350*330*360	80,000	13.50

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{smmin}) -Temperature Max(T _{smmax}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{smmax} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

FFM101-AF THRU FFM107-AF**High reliability test capabilities**

Item Test	Conditions	Reference
1. Solder Resistance	at $260 \pm 5^\circ\text{C}$ for 10 ± 2 sec.	MIL-STD-750D METHOD-2031
2. Solderability	at $245 \pm 5^\circ\text{C}$ for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R = 80\%$ rate at $T_J = 150^\circ\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A = 25^\circ\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^\circ\text{C}$, $I_F = I_O$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A = 121^\circ\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to $+125^\circ\text{C}$ dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Forward Surge	8.3ms single half sine-wave , one surge.	MIL-STD-750D METHOD-4066-2
9. Humidity	at $T_A = 85^\circ\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
10. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031